STMUX7000

## 7-channel MUX/DEMUX for analog video signal

## Features

- Low $R_{O N}: 4.0 \Omega$ typical

■ $\mathrm{V}_{\mathrm{CC}}$ operating range: 3.0 to 3.6 V
■ Enhanced ESD protection: $>8 \mathrm{kV}$ (contact) and 8 kV (HBM)
■ Channel on capacitance: 7.8 pF typical

- Designed for VGA signal switching
- Integrated switches for RGB, HSYNC, VSYNC and DDC signals
■ Very low crosstalk: -45 dB at 250 MHz
■ > $1000 \mathrm{MHz}-3 \mathrm{~dB}$ typical bandwidth (or data frequency)
- Low power mode for minimum power consumption
■ Package: QFN32L


## Applications

■ Audio/video switching


## Description

The STMUX7000 is a 7-channel multiplexer/demultiplexer low $\mathrm{R}_{\mathrm{ON}}$ bidirectional designed for analog video signal, such as VGA. It is designed for very low crosstalk, and high bandwidth to maintain high signal integrity.

The analog video signal multiplexed from one of two selected sources in the notebook and docking station while the unselected switch goes to $\mathrm{Hi}-\mathrm{Z}$ status.

The device is also protected against high ESD that supports up to 8 kV contact on all I/O pins.

The device can be put into low power mode consuming minimum power.

Table 1. Device summary

| Order code | Package | Packing |
| :---: | :---: | :---: |
| STMUX7000QTR | QFN32 $(3 \times 6 \times 0.8 \mathrm{~mm})$ | Tape and reel |

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## 1 <br> Pin description

Figure 1. Pin connection (top through view)


Table 2. Pin description

| Pin | Symbol | Name and function |
| :---: | :---: | :--- |
| 8 | SEL 1 | Selecion for bit 0, 1, 2, 3, 4 |
| 30 | SEL 2 | Selection for bit 5, 6 |
| $1,2,5,6,7,9,10$ | A0, A1, A2, A3, A4, A5, A6 | 8-bit bus |
| $4,16,23,29,32$ | VDD | Supply voltage |
| $3,11,28$ | GND | Ground |
| $27,25,22,20,18,14,12$ | 0B1, 1B1, 2B1, 3B1, 4B1, 5B1, <br> $6 B 1$ | 8 8-bit multiplexed to bus 1 |
| $26,24,21,19,17,15,13$ | 0B2, 1B2, 2B2, 3B2, 4B2, 5B2, <br> 6B2 | 8-bit multiplexed to bus 2 |
| 31 | LP | Low power mode enable |

Figure 2. Input equivalent circuit


Table 3. Bit 0, 1, 2, 3, 4 switch function table

| LP | SEL 1 | Function |
| :---: | :---: | :--- |
| L | L | Bit 0, 1, 2, 3, 4 multiplexed to bus 1, bus 2 in $\mathrm{Hi}-\mathrm{Z}$ |
| L | H | Bit 0, 1, 2, 3, 4 multiplexed to bus 2, bus 1 in $\mathrm{Hi}-\mathrm{Z}$ |
| H | X | Bus 1 and 2 in $\mathrm{Hi}-\mathrm{Z}$ |

Table 4. Bit 5, 6 switch function table

| LP | SEL 2 | Function |
| :---: | :---: | :--- |
| L | L | Bit 5,6 multiplexed to bus 1, bus 2 in Hi-Z |

Table 4. Bit 5, 6 switch function table

| LP | SEL 2 | Function |
| :---: | :---: | :--- |
| L | H | Bit 5,6 multiplexed to bus 2, bus 1in Hi-Z |
| H | X | Bus 1 and 2 in Hi-Z |

## 2 Maximum rating

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 5. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage to ground | -0.5 to 4.6 | V |
| $\mathrm{~V}_{\mathrm{IO}}$ | DC input output voltage | -0.5 to 4.6 | V |
| $\mathrm{~V}_{\mathrm{IC}}$ | DC control input voltage | -0.5 to 4.6 | V |
| $\mathrm{I}_{\mathrm{O}}$ | DC output current ${ }^{(1)}$ | 120 | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Power dissipation | 0.5 | W |
| $\mathrm{~T}_{\text {stg }}$ | Storage temperature | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead temperature (10 sec) | 300 | ${ }^{\circ} \mathrm{C}$ |

1. If $\mathrm{V}_{1 \mathrm{O}} \times \mathrm{I}_{\mathrm{O}}$ does not exceed the maximum limit of $\mathrm{P}_{\mathrm{D}}$.

### 2.1 Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Value |  |  | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage to ground | 3 | - |  | V |
| $\mathrm{~V}_{\mathrm{IC}}$ | DC control input voltage (SEL, LP) | 0 | - | 5 | V |
| $\mathrm{~V}_{\mathrm{IO}}$ | DC input/output voltage | 0 | - | $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{T}_{\mathrm{A}}$ | Operating temperature | -40 | - | 85 | ${ }^{\circ} \mathrm{C}$ |

## 3 Electrical characteristics

Table 7. $\quad \mathrm{DC}$ electrical characteristics ( $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -40 to $85{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Voltage input high (SEL, LP) | High level guaranteed | 2 | - | - | V |
| $\mathrm{V}_{\text {IL }}$ | Voltage input low (SEL, LP) | Low level guaranteed | -0.5 | - |  | V |
| $\mathrm{V}_{\text {IK }}$ | Clamp diode voltage (SEL, LP) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{IN}}=-18 \mathrm{~mA} \end{aligned}$ | - | -0.8 | -1.2 | V |
| $\mathrm{IIH}^{\text {H }}$ | Input high current (SEL, LP) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ |  |  | $\pm 5$ | $\mu \mathrm{A}$ |
| $I_{\text {IL }}$ | Input low current (SEL, LP) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{GND} \end{aligned}$ |  | - | $\pm 5$ | $\mu \mathrm{A}$ |
| $\mathrm{IOFF}_{(\mathrm{SW})}{ }^{(1)}$ | Leakage current through the switch common terminals (A to H) (LED1 to LED3) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \text { A to } \mathrm{H}=\mathrm{V}_{\mathrm{CC}} \\ & \text { LED1 to } \mathrm{LED} 3=\mathrm{V}_{\mathrm{CC}} \\ & \text { A0 to } \mathrm{H0}=0 \mathrm{~V} \\ & \text { A1 to } \mathrm{H} 1=\text { floating } \\ & \text { LEDx_0 }=0 \mathrm{~V} \\ & \text { LEDx1 }=\text { floating } \\ & \text { SEL }=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\operatorname{IOFF}_{(\mathrm{SEL}}$, LP) | SEL, LP pin leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V} \\ & \mathrm{SEL}=0 \text { to } 3.6 \mathrm{~V} \end{aligned}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\mathrm{ON}}$ | Switch ON resistance ${ }^{(2)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=0 \text { to } 1.2 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \\ & \hline \end{aligned}$ | - | 4.0 | 6.5 | $\Omega$ |
| $R_{\text {FLAT }}$ | ON resistance flatness ${ }^{(2)}$ (3) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}} \text { at } 0 \text { and } 1.2 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \end{aligned}$ | - | 0.5 | - | $\Omega$ |
| $\Delta \mathrm{R}_{\text {ON }}$ | ON resistance match between channel $\underset{(2)(4)}{\Delta \mathrm{R}_{\mathrm{ON}}}=\mathrm{R}_{\mathrm{ONMAX}}-\mathrm{R}_{\mathrm{ONMIN}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=0 \text { to } 1.2 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{N}}=-40 \mathrm{~mA} \end{aligned}$ | - | 0.4 | 1 | $\Omega$ |

[^0]Table 8. Capacitance ( $\mathrm{T}_{\mathrm{A}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}, \mathrm{f}=\mathbf{1 M H z}$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{C}_{\text {IN }}$ | SEL, LP pin input capacitance ${ }^{(1)}$ | $\begin{aligned} & D C=0.25 \mathrm{~V} \\ & A C=0.5 \mathrm{~V} P \mathrm{P} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | 2 | 3 | pF |
| $\mathrm{C}_{\text {OFF }}$ | Switch off capacitance ${ }^{(2)}$ | $\begin{aligned} & \mathrm{DC}=0.25 \mathrm{~V} \\ & \mathrm{AC}=0.5 \mathrm{~V} P \mathrm{PP} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | 2.8 | 6.5 | pF |
| $\mathrm{C}_{\mathrm{ON}}$ | Switch on capacitance ${ }^{(3)}$ | $\begin{aligned} & D C=0.25 \mathrm{~V} \\ & A C=0.5 \mathrm{~V} P \mathrm{P} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | 7.8 |  | pF |

1. Refer to Figure 5 on page 11.
2. Refer to Figure 6 on page 11.
3. Refer to Figure 7 on page 12.

Table 9. Power supply characteristics

| Symbol | Parameter | Test condition |  | Value |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -40 to $85{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ | Max |  |
| $I_{C C}$ | Active mode power supply current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } \\ & \mathrm{GND}, \mathrm{LP}=\mathrm{GND} \end{aligned}$ | - | 150 | 500 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Low power mode power supply current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } \\ & \mathrm{GND}, \mathrm{LP}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | - | 10 | 15 | $\mu \mathrm{A}$ |

Table 10. Dynamic electrical characteristics ( $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -40 to $85{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{X}_{\text {talk }}$ | Crosstalk ${ }^{(1)}$ | $\begin{aligned} & R_{L}=50 \Omega \quad R_{S}=50 \Omega \\ & f=250 \mathrm{MHz} \end{aligned}$ | - | -45 | - | dB |
| $\mathrm{O}_{\text {IRR }}$ | Off isolation ${ }^{(2)}$ | $\begin{aligned} & R_{L}=50 \Omega \quad R_{S}=50 \Omega \\ & \mathrm{f}=250 \mathrm{MHz} \end{aligned}$ | - | -32 | - | dB |
| BW | -3 dB bandwidth ${ }^{(3)}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega \quad \mathrm{R}_{\mathrm{S}}=50 \Omega \\ & 0<\mathrm{V}_{\mathrm{IN}} \leq 1.2 \mathrm{~V} \end{aligned}$ | - | 1000 | - | MHz |

1. Refer to Figure 9 on page 13.
2. Refer to Figure 10 on page 14.
3. Refer to Figure 8 on page 12.

Table 11. Switching characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max |  |
| $t_{\text {PD }}$ | Propagation delay | $\mathrm{V}_{\mathrm{CC}}=3$ to 3.6 V | - | 0.25 | - | ns |
| $\begin{aligned} & \mathrm{t}_{\mathrm{PZH}}, \\ & \mathrm{t}_{\mathrm{PZL}} \end{aligned}$ | Line enable time, SE to x to x 0 or x to x 1 | $\mathrm{V}_{\mathrm{CC}}=3$ to 3.6 V $1 \mathrm{~K} \Omega$ pull up/down resistor at xb 1 or xB 2 | 0.5 | 6.5 | 15 | ns |
| $\begin{aligned} & \mathrm{t}_{\mathrm{PHZ}}, \\ & \mathrm{t}_{\mathrm{PLZ}} \end{aligned}$ | Line disable time, SE to x to x 0 or x to x 1 | $\mathrm{V}_{\mathrm{CC}}=3$ to 3.6 V $1 \mathrm{~K} \Omega$ pull up/down resistor at xb1 or xB2 | 0.5 | 16 |  | ns |
| ${ }^{\text {tsk(0) }}$ | Output skew between center port to any other port | $\mathrm{V}_{C C}=3$ to 3.6 V | - | 0.1 | $0.2$ | ns |
| $\mathrm{t}_{\text {SK(P) }}$ | Skew between opposite transition of the same output ( $\mathrm{t}_{\mathrm{PHL}}, \mathrm{t}_{\mathrm{PLH}}$ ) | $\mathrm{V}_{C C}=3$ to 3.6 V |  | 0.1 | 0.2 | ns |

Table 12. ESD performance

| Symbol | Test condition | Value |  |  | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max |  |
| ESD | Contact discharge ${ }^{(1)}$ <br> IEC61000-4-2 | - | $\pm 8$ | - | kV |
|  | Human body model <br> (JESD22-A114) | - | $\pm 8$ | - | kV |

1. Refer to Figure 3: Diagram for suggested VDD decoupling on page 10.

Figure 3. Diagram for suggested $\mathrm{V}_{\mathrm{DD}}$ decoupling


Note: 100 nF Capacitors must be used as local bypass capacitors between the adjacent VDD and GND pairs (total 7)

1. Applicable for system level ESD test

Figure 4. Test circuit for leakage current (loff)


Figure 5. Test circuit for SEL pin input capacitance ( $C_{\text {IN }}$ )


Figure 6. Test circuit for switch off capacitance ( $\mathrm{C}_{\mathrm{OFF}}$ )


Figure 7. Test circuit for switch on capacitance ( $\mathrm{C}_{\mathrm{ON}}$ )


Figure 8. Test circuit for bandwidth measurement (BW)


Frequency response is measured at the output of the ON channel. For example, when $\mathrm{V}_{\text {SEL1 }}=0$ and AO is the input, the output is measured at OB1. All unused analog I/O ports are left open.

HP8753ES setup:
Average $=4$
$\mathrm{R}_{\mathrm{BW}}=3 \mathrm{kHz}$
$\mathrm{V}_{\text {BIAS }}=0.35 \mathrm{~V}$
$\mathrm{ST}=2 \mathrm{~s}$
$\mathrm{P} 1=0 \mathrm{dBm}$
Figure 9. Test circuit for crosstalk measurement ( $\mathrm{x}_{\text {talk }}$ )


Crosstalk is measured at the output of the non-adjacent ON channel. For example, when $\mathrm{V}_{\text {SEL } 1}=0$, and A 1 is the input, the output is measured at A 3 . All unused analog input ports are connected to GND and output ports are left open.

HP8753ES setup:
Average = 4
$\mathrm{R}_{\mathrm{BW}}=3 \mathrm{kHz}$
$\mathrm{V}_{\mathrm{BIAS}}=0.35 \mathrm{~V}$
ST = 2 s
$\mathrm{P} 1=0 \mathrm{dBm}$

Figure 10. Test circuit for off isolation measurement ( $O_{\text {IRR }}$ )


Off isolation is measured at the output of the OFF channel. For example, when $\mathrm{V}_{\mathrm{SEL} 1}=0$, and A1 is the input, the output is measured at 1B2. All unused analog input ports are connected to GND and output ports are left open.
HP8753ES setup:
Average $=4$
$\mathrm{R}_{\mathrm{BW}}=3 \mathrm{kHz}$
$\mathrm{V}_{\mathrm{BIAS}}=0.35 \mathrm{~V}$
ST = 2 s
$\mathrm{P} 1=0 \mathrm{dBm}$

## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK ${ }^{\circledR}$ packages, depending on their level of environmental compliance. ECOPACK ${ }^{\circledR}$ specifications, grade definitions and product status are available at: www.st.com. ECOPACK ${ }^{\circledR}$ is an ST trademark.

Figure 11. Package outline for QFN32L ( $3 \times 6 \times 0.8 \mathrm{~mm}$ ) - pitch 0.4 mm


Table 13. Mechanical data for QFN32L ( $3 \times 6 \times 0.8 \mathrm{~mm}$ ) - pitch 0.4 mm

| Symbol | Millimeters |  |  |
| :---: | :---: | :---: | :---: |
|  | Min | Typ | Max |
| A | 0.70 | 0.80 | 0.90 |
| A1 | 0.00 | 0.05 | 0.08 |
| A3 |  | 0.25 |  |
| T | 0.00 |  | 12.00 |
| b | 0.15 | 0.20 | 0.25 |
| e |  | 0.40 |  |
| e1 |  | 4.00 |  |
| K |  | 0.75 |  |
| D |  | 3.00 | 0.00 |
| E | 0.25 | 0.30 | 1.60 |
| L2 | 1.50 | 3.90 | 4.00 |

Figure 12. Footprint recommendation

## RECOMMENDED FOOTPRINT



Figure 13. Carrier tape and reel information


## 5 Revision history

Table 14. Document revision history

| Date | Revision | Changes |
| :---: | :---: | :--- |
| 23-Apr-2010 | 1 | Initial release. |
| 16-Jun-2010 | 2 | Modified: Figure 12. |
| 09-Mar-2011 | 3 | Updated: Table 8, Table 11 and Table 12. |

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$\underline{M A X 4545 C W P+}$ MAX4545EAP+ MAX4545EPP+ MAX4546ESE+ MAX4547CEE+ MAX4547CSE +


[^0]:    1. Refer to Figure 4: Test circuit for leakage current (IOFF) on page 10
    2. Measured by voltage drop between channels at indicated current through the switch. ON resistance is determined by the lower of the voltages.
    3. Flatness is defined as the difference between the $R_{\text {ONMAX }}$ and $R_{\text {ONMIN }}$ of ON resistance over the specified range.
    4. $\Delta R_{\mathrm{ON}}$ measured at same $\mathrm{V}_{\mathrm{CC}}$, temperature and voltage level.
